Automotive N-Channel 20 V (D-S) 175 °C MOSFET

PRODUCT SUMMARY	
V_{DS} (V)	20
$R_{DS(on)}$ (Ω) at V_{GS} = 10 V	0.0035
$R_{DS(on)}$ (Ω) at V_{GS} = 4.5 V	0.0045
I_D (A)	100
Configuration	Single
Package	TO-252

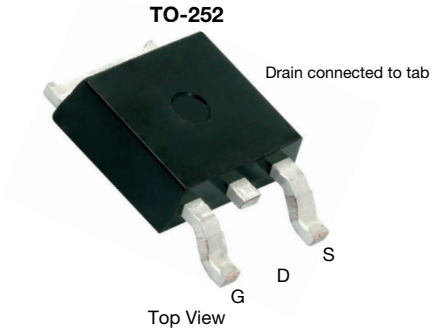
FEATURES

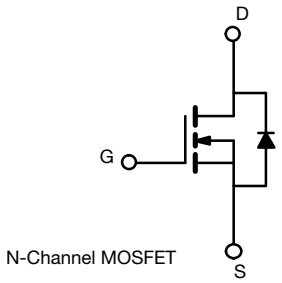
- TrenchFET® power MOSFET
- 100 % R_g and UIS tested
- AEC-Q101 qualified [d]
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

AUTOMOTIVE GRADE

RoHS COMPLIANT

HALOGEN FREE





ABSOLUTE MAXIMUM RATINGS (T_C = 25 °C, unless otherwise noted)				
PARAMETER		SYMBOL	LIMIT	UNIT
Drain-Source Voltage		V_{DS}	20	V
Gate-Source Voltage		V_{GS}	± 20	
Continuous Drain Current	T_C = 25 °C [a]	I_D	100	A
	T_C = 125 °C		65	
Continuous Source Current (Diode Conduction)		I_S	75	
Pulsed Drain Current [b]		I_{DM}	300	
Single Pulse Avalanche Current	L = 0.1 mH	I_{AS}	45	
Single Pulse Avalanche Energy		E_{AS}	101	mJ
Maximum Power Dissipation [b]	T_C = 25 °C	P_D	83	W
	T_C = 125 °C		27	
Operating Junction and Storage Temperature Range		T_J, T_{stg}	-55 to +175	°C

THERMAL RESISTANCE RATINGS				
PARAMETER		SYMBOL	LIMIT	UNIT
Junction-to-Ambient	PCB Mount [c]	R_{thJA}	50	°C/W
Junction-to-Case (Drain)		R_{thJC}	1.8	

Notes

a. Package limited.
b. Pulse test; pulse width ≤ 300 µs, duty cycle ≤ 2 %.
c. When mounted on 1" square PCB (FR4 material).
d. Parametric verification ongoing.

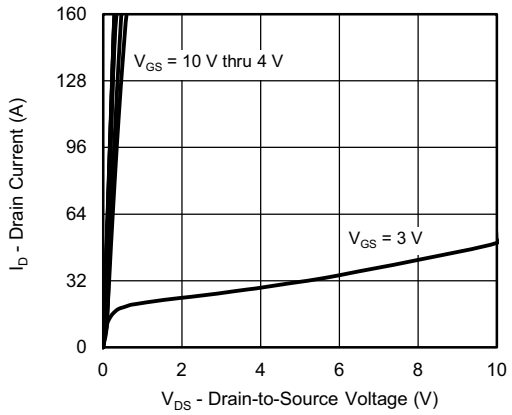
SPECIFICATIONS (T_C = 25 °C, unless otherwise noted)							
PARAMETER	**SYMBOL**	**TEST CONDITIONS**		**MIN.**	**TYP.**	**MAX.**	**UNIT**
Static							
Drain-Source Breakdown Voltage	V_{DS}	V_{GS} = 0 V, I_D = 250 µA		20	-	-	V
Gate-Source Threshold Voltage	$V_{GS(th)}$	V_{DS} = V_{GS}, I_D = 250 µA		1.5	2.0	2.5	
Gate-Source Leakage	I_{GSS}	V_{DS} = 0 V, V_{GS} = ± 20 V		-	-	± 100	nA
Zero Gate Voltage Drain Current	I_{DSS}	V_{GS} = 0 V	V_{DS} = 20 V	-	-	1	µA
		V_{GS} = 0 V	V_{DS} = 20 V, T_J = 125 °C	-	-	50	
		V_{GS} = 0 V	V_{DS} = 20 V, T_J = 175 °C	-	-	250	
On-State Drain Current [a]	$I_{D(on)}$	V_{GS} = 10 V	V_{DS} ≥ 5 V	50	-	-	A
Drain-Source On-State Resistance [a]	$R_{DS(on)}$	V_{GS} = 10 V	I_D = 30 A	-	0.0020	0.0035	Ω
		V_{GS} = 10 V	I_D = 30 A, T_J = 125 °C	-	-	0.0050	
		V_{GS} = 10 V	I_D = 30 A, T_J = 175 °C	-	-	0.0058	
		V_{GS} = 4.5 V	I_D = 20 A	-	0.0030	0.0045	
Forward Transconductance [b]	g_{fs}	V_{DS} = 15 V, I_D = 30 A		-	186	-	S
Dynamic [b]							
Input Capacitance	C_{iss}	V_{GS} = 0 V	V_{DS} = 10 V, f = 1 MHz	-	4300	5500	pF
Output Capacitance	C_{oss}			-	1350	1700	
Reverse Transfer Capacitance	C_{rss}			-	585	800	
Total Gate Charge [c]	Q_g	V_{GS} = 10 V	V_{DS} = 10 V, I_D = 50 A	-	70	110	nC
Gate-Source Charge [c]	Q_{gs}			-	21	-	
Gate-Drain Charge [c]	Q_{gd}			-	11	-	
Gate Resistance	R_g	f = 1 MHz		1.1	2.3	3.5	Ω
Turn-On Delay Time [c]	$t_{d(on)}$	V_{DD} = 10 V, R_L = 0.2 Ω I_D ≅ 50 A, V_{GEN} = 10 V, R_g = 1 Ω		-	15	25	ns
Rise Time[c]	t_r			-	5	10	
Turn-Off Delay Time [c]	$t_{d(off)}$			-	38	60	
Fall Time [c]	t_f			-	15	25	
Source-Drain Diode Ratings and Characteristics [b]							
Pulsed Current [a]	I_{SM}			-	-	300	A
Forward Voltage	V_{SD}	I_F = 50 A, V_{GS} = 0 V		-	0.86	1.2	V

Notes

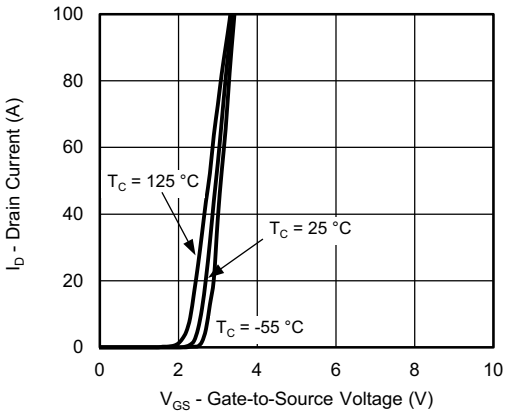
a. Pulse test; pulse width ≤ 300 µs, duty cycle ≤ 2 %.
b. Guaranteed by design, not subject to production testing.
c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

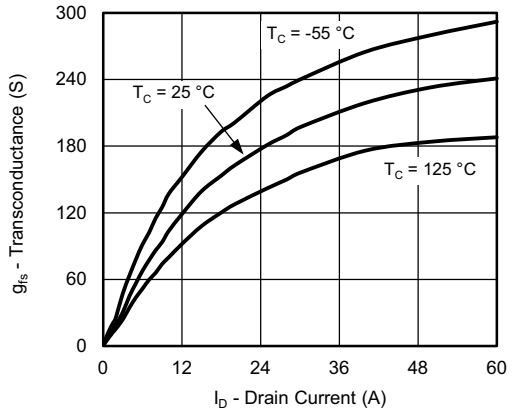
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



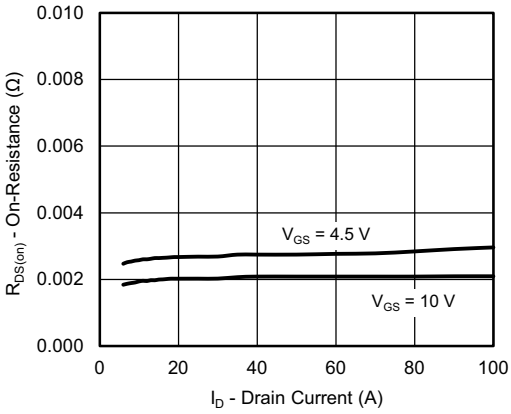
Output Characteristics



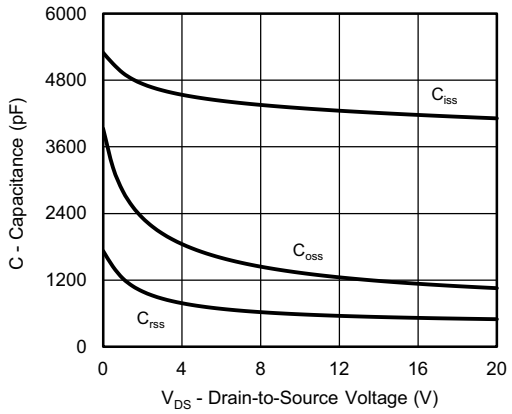
Transfer Characteristics



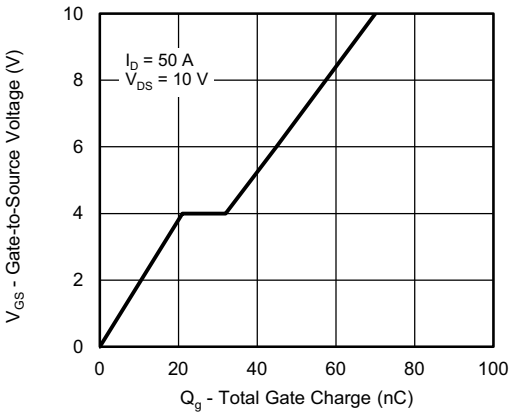
Transconductance



On-Resistance vs. Drain Current

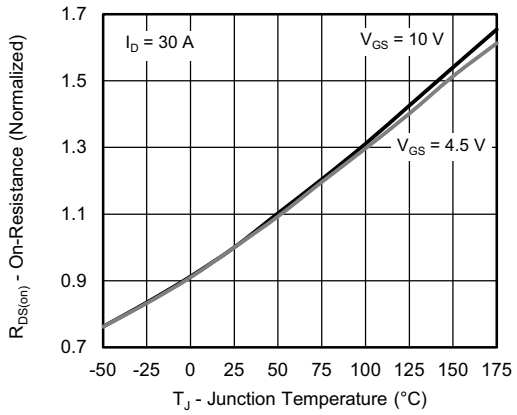


Capacitance

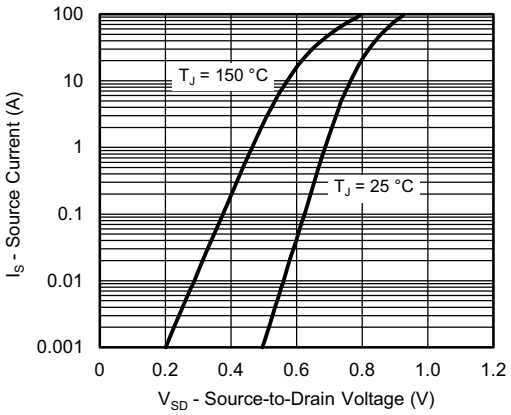


Gate Charge

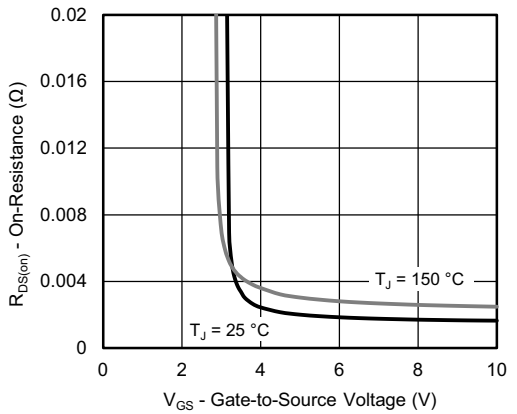
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



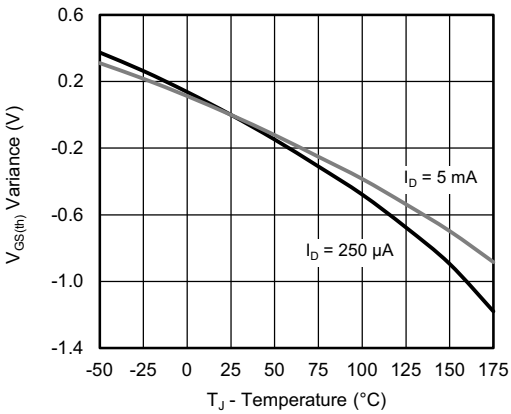
On-Resistance vs. Junction Temperature



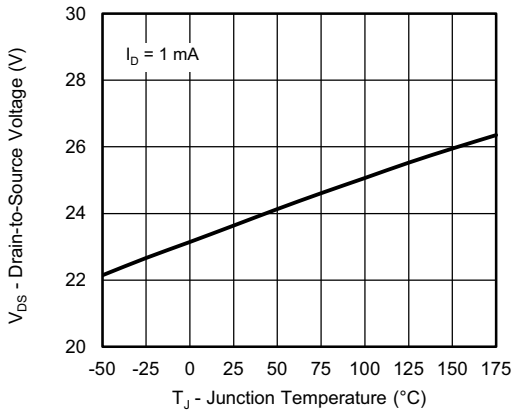
Source Drain Diode Forward Voltage



On-Resistance vs. Gate-to-Source Voltage

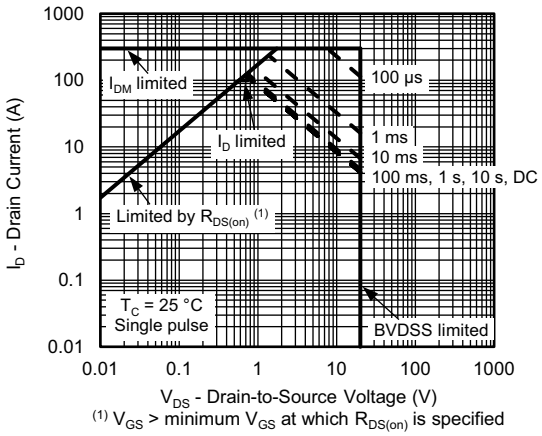


Threshold Voltage

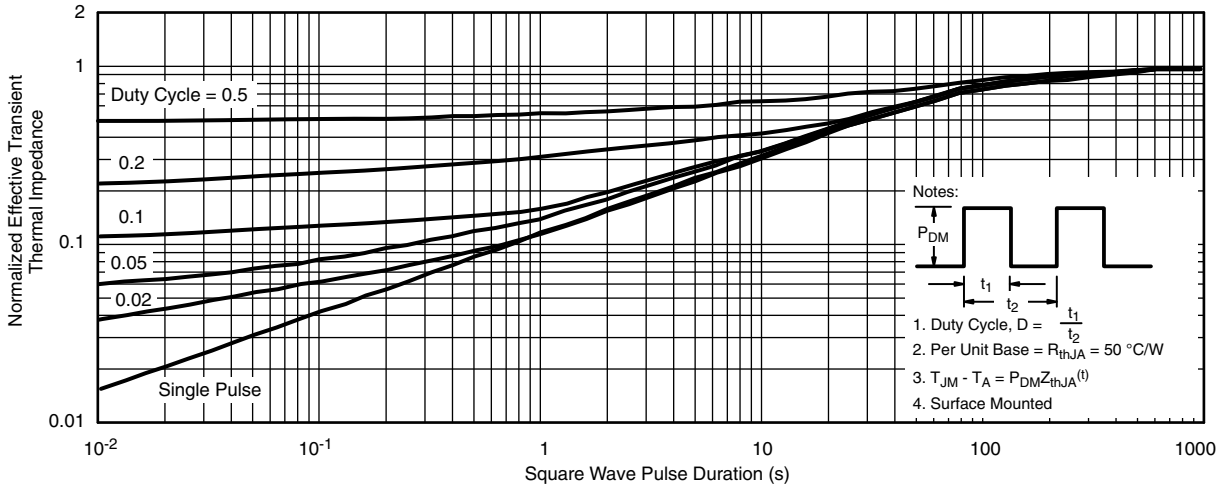


Breakdown Voltage vs. Junction Temperature

THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)

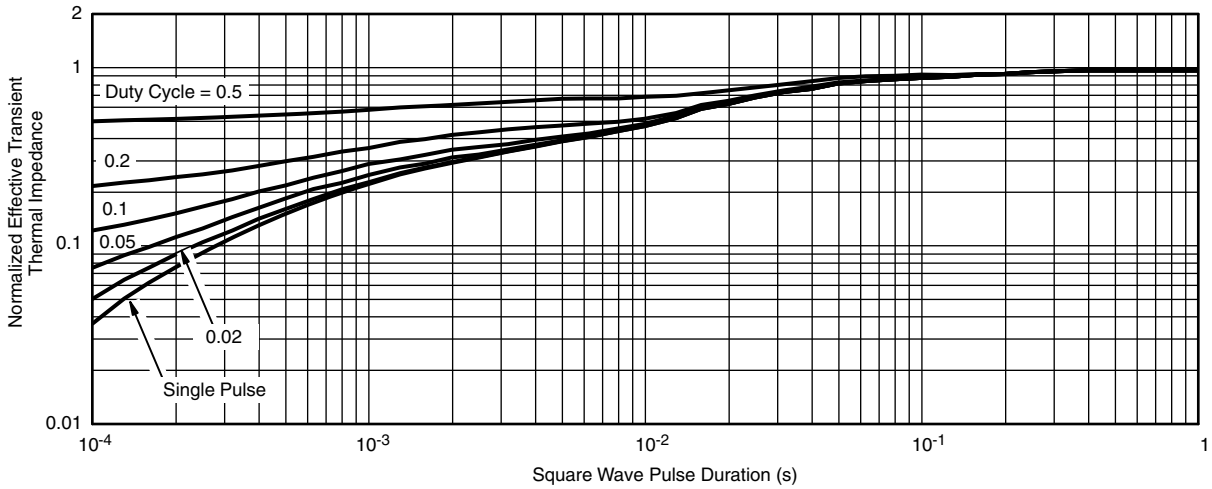


Safe Operating Area



Normalized Thermal Transient Impedance, Junction-to-Ambient

THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case

Note

- The characteristics shown in the two graphs
  - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
  - Normalized Transient Thermal Impedance Junction-to-Case (25 °C)

  are given for general guidelines only to enable the user to get a “ball park” indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

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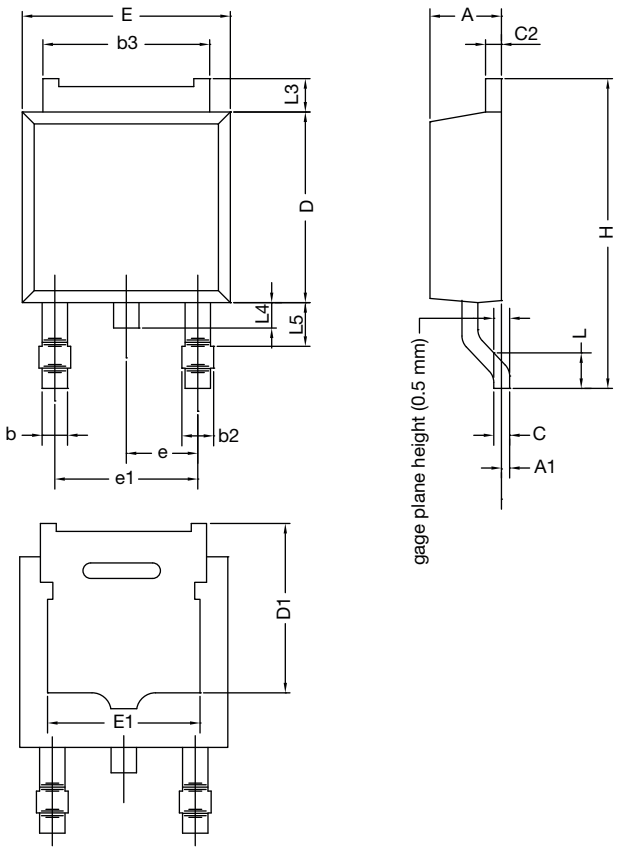
TO-252AA Case Outline

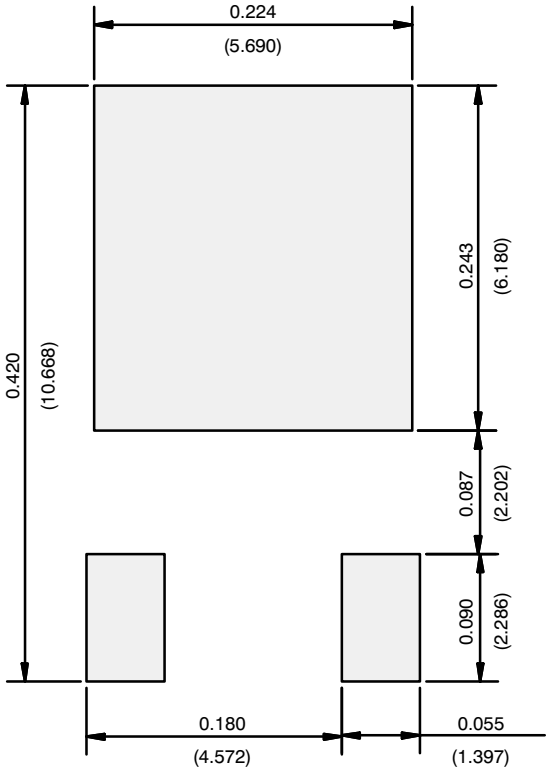


	MILLIMETERS		INCHES	
DIM.	MIN.	MAX.	MIN.	MAX.
A	2.18	2.38	0.086	0.094
A1	-	0.127	-	0.005
b	0.64	0.88	0.025	0.035
b2	0.76	1.14	0.030	0.045
b3	4.95	5.46	0.195	0.215
C	0.46	0.61	0.018	0.024
C2	0.46	0.89	0.018	0.035
D	5.97	6.22	0.235	0.245
D1	4.10	-	0.161	-
E	6.35	6.73	0.250	0.265
E1	4.32	-	0.170	-
H	9.40	10.41	0.370	0.410
e	2.28 BSC		0.090 BSC	
e1	4.56 BSC		0.180 BSC	
L	1.40	1.78	0.055	0.070
L3	0.89	1.27	0.035	0.050
L4	-	1.02	-	0.040
L5	1.01	1.52	0.040	0.060
ECN: T13-0592-Rev. A, 02-Sep-13 DWG: 6019				

Note

- Dimension L3 is for reference only.

RECOMMENDED MINIMUM PADS FOR DPAK (TO-252)



Recommended Minimum Pads
Dimensions in Inches/(mm)

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